

## Up to 24V Supply, 4-A Dual Channel High Speed Low Side Driver

### FEATURES

- Wide Supply Voltage Range: 4.5V - 24V
- 4A Peak Source Current and 4A Peak Sink Current
- Negative Input Voltage Capability: Down to -5V
- TTL Compatible Input Logic Threshold
- Propagation Delay: 13ns
- Typical Rising and Falling Times: 8ns
- Thermal Shutdown Protection: 170°C
- Available in SOP-8 Package

### APPLICATIONS

- IGBT/MOSFET Gate Driver
- Variable Frequency-Drive (VFD)
- Switching Power Supply
- Motor Control
- Solar Power Inverter

### DESCRIPTION

The SCT52245 is a wide supply, dual channel, high speed, low side gate drivers for both power MOSFET and IGBT. Each channel can source and sink 4A peak current along with rail-to-rail output capability. The 24V power supply rail enhances the driver output ringing endurance during the power device transition.

The minimum 13ns input to output propagation delay enables the SCT52245 suitable for high frequency power converter application.

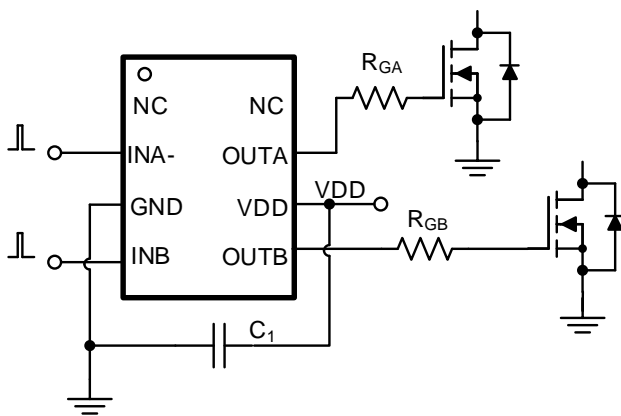
The SCT52245 features wide input hysteresis that is compatible for TTL low voltage logic. The SCT52245 has the capability to handle negative input down to -5V, which increases the input noise immunity.

The SCT52245 has very low quiescent current that reduces the stand-by loss in the power converter. The SCT52245 each channel driver adopts non-overlap driver design to avoid the shoot-through of output stage.

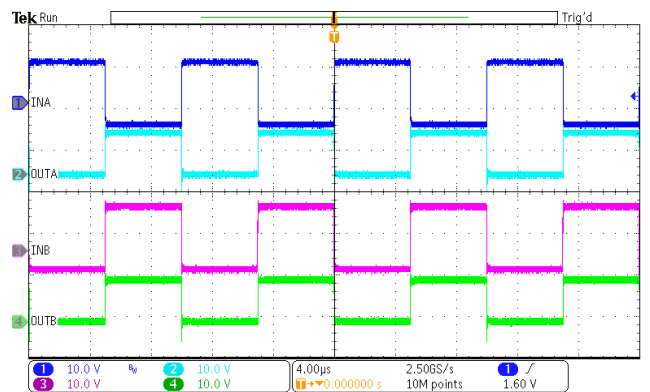
The SCT52245 features 170°C thermal shut down. The SCT52245 is available in SOP-8 package

### TYPICAL APPLICATION

SCT52245 Typical Application



Application Waveform



## REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Revision 1.0: Production

Revision 1.1: Update DEVICE ORDER INFORMATION

## DEVICE ORDER INFORMATION

ORDERABLE DEVICE	PACKAGING TYPE	STANDARD PACK QTY	PACKAGE MARKING	PINS	PACKAGE DESCRIPTION
SCT52245STDR	Tape & Reel	4000	2245	8	SOP-8L

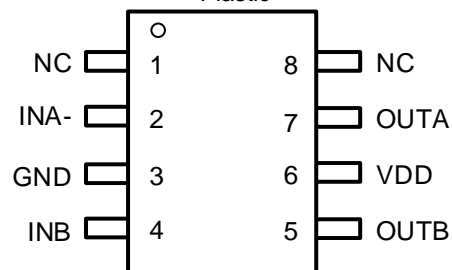
## ABSOLUTE MAXIMUM RATINGS

Over operating free-air temperature unless otherwise noted<sup>(1)</sup>

DESCRIPTION	MIN	MAX	UNIT
INA-, INB	-5	26	V
OUTA, OUTB	-0.3	VDD+0.3	V
VDD	-0.3	26	V
Operating junction temperature T <sub>J</sub> <sup>(2)</sup>	-40	150	°C
Storage temperature T <sub>STG</sub>	-65	150	°C

## PIN CONFIGURATION

Top View: SOP-8pin  
Plastic



- (1) Stresses beyond those listed under Absolute Maximum Rating may cause device permanent damage. The device is not guaranteed to function outside of its Recommended Operation Conditions.
- (2) The IC includes over temperature protection to protect the device during overload conditions. Junction temperature will exceed 150°C when over temperature protection is active. Continuous operation above the specified maximum operating junction temperature will reduce lifetime.

## PIN FUNCTIONS

NAME	NO.	PIN FUNCTION
NC	1	No Connection.
INA-	2	Channel A logic input, TTL compatible. Floating logic low.
GND	3	Power ground. Must be soldered directly to ground plane for thermal performance improvement and electrical contact.
INB	4	Channel B logic input, TTL compatible. Floating logic low.
OUTB	5	Channel B gate driver output
VDD	6	Power Supply, must be locally bypassed by the ceramic cap.
OUTA	7	Channel A gate driver output
NC	8	No Connection.

## RECOMMENDED OPERATING CONDITIONS

Over operating free-air temperature range unless otherwise noted

PARAMETER	DEFINITION	MIN	MAX	UNIT
V <sub>DD</sub>	Supply voltage range	4.5	24	V
V <sub>INA-,INB</sub>	Input voltage range	-5	24	
T <sub>J</sub>	Operating junction temperature	-40	150	°C

## ESD RATINGS

PARAMETER	DEFINITION	MIN	MAX	UNIT
V <sub>ESD</sub>	Human Body Model (HBM), per ANSI-JEDEC-JS-001-2014 specification, all pins <sup>(1)</sup>	-2	+2	kV
	Charged Device Model (CDM), per ANSI-JEDEC-JS-002-2014specification, all pins <sup>(1)</sup>	-0.5	+0.5	kV

(1) HBM and CDM stressing are done in accordance with the ANSI/ESDA/JEDEC JS-001-2014 specification

## THERMAL INFORMATION

PARAMETER	THERMAL METRIC	SOP-8L	UNIT
R <sub>θJA</sub>	Junction to ambient thermal resistance <sup>(1)</sup>	130	°C/W
R <sub>θJC</sub>	Junction to case thermal resistance <sup>(1)</sup>	80	

(1) SCT provides R<sub>θJA</sub> and R<sub>θJC</sub> numbers only as reference to estimate junction temperatures of the devices. R<sub>θJA</sub> and R<sub>θJC</sub> are not a characteristic of package itself, but of many other system level characteristics such as the design and layout of the printed circuit board (PCB) on which the SCT52245 is mounted, and external environmental factors. The PCB board is a heat sink that is soldered to the leads and thermal pad of the SCT52245. Changing the design or configuration of the PCB board changes the efficiency of the heat sink and therefore the actual R<sub>θJA</sub> and R<sub>θJC</sub>.

# SCT52245

## ELECTRICAL CHARACTERISTICS

V<sub>DD</sub>=12V, T<sub>J</sub>=-40°C~150°C, typical values are tested under 25°C.

SYMBOL	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
<b>Power Supply and Output</b>						
V <sub>DD</sub>	Operating supply voltage		4.5		24	V
V <sub>DD_UVLO</sub>	Input UVLO Hysteresis	V <sub>DD</sub> rising		4.2 300	4.5	V mV
I <sub>q</sub>	Supply current	V <sub>DD</sub> =12V, INA- =INB =GND		130		uA
		V <sub>DD</sub> =12V, INA- =INB =12V		190		uA
<b>INPUTS</b>						
V <sub>INA-,INB_H</sub>	Input logic high threshold Output low for inverting input Output high for non-inverting input			2.1	2.4	V
V <sub>INA-,INB_L</sub>	Input logic low threshold Output high for inverting input Output low for non-inverting input		0.8	1		V
V <sub>IN_Hys</sub>	Hysteresis			1.1		V
<b>OUTPUTS</b>						
V <sub>DD_VOH</sub>	Output – output high voltage	I <sub>OUT</sub> = - 10mA			150	mV
V <sub>OL</sub>	Output low voltage	I <sub>OUT</sub> = 10mA			10	mV
I <sub>SINK/SRC</sub>	Output sink/source peak current	C <sub>Load</sub> =10nF, F <sub>SW</sub> =1kHz		4		A
R <sub>OH</sub>	Output pull high resistance (only PMOS ON)	I <sub>OUT</sub> = - 10mA	5	9	18	Ω
R <sub>OL</sub>	Output pull low resistance	I <sub>OUT</sub> = 10mA	0.3	0.6	1.2	Ω
<b>Timing</b>						
T <sub>R</sub>	Output rising time	C <sub>Load</sub> =1nF		8	20	ns
T <sub>F</sub>	Output falling time	C <sub>Load</sub> =1nF		8	20	ns
T <sub>D_IN</sub>	Input to output propagation delay, Rising edge			13	25	ns
	Input to output propagation delay, Falling edge			13	25	ns
T <sub>MIN_ON</sub>	Minimum input pulse width	C <sub>Load</sub> =1nF		20	30	ns
<b>Protection</b>						
T <sub>SD</sub>	Thermal shutdown threshold*	T <sub>J</sub> rising		170		°C
	Hysteresis			25		°C

\*Derived from bench characterization

## TYPICAL CHARACTERISTICS

$V_{IN}=12V$ ,  $T_A=25^{\circ}C$ .

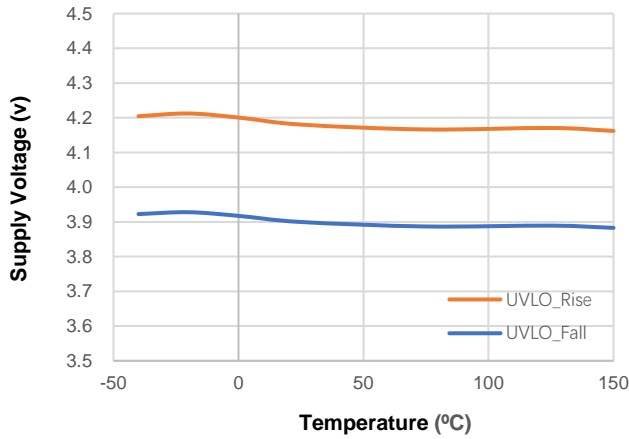


Figure 1. UVLO vs Temperature

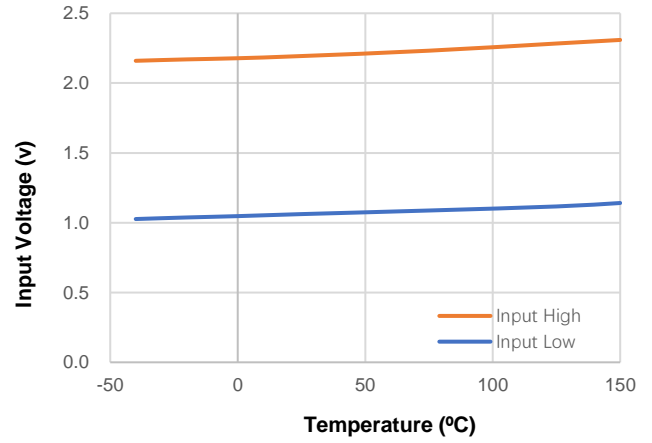


Figure 2. Input Threshold vs Temperature

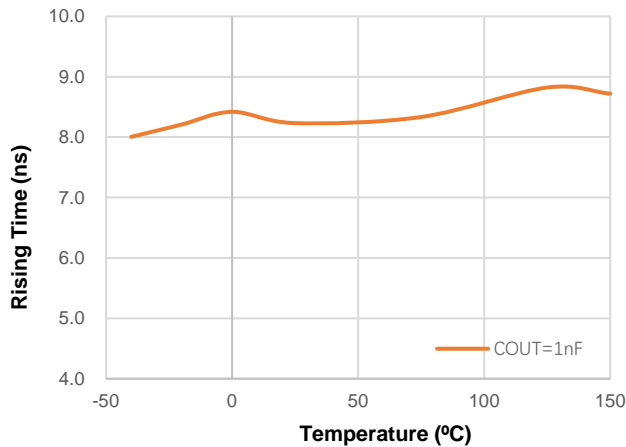


Figure 3 Output Rising Time vs Temperature

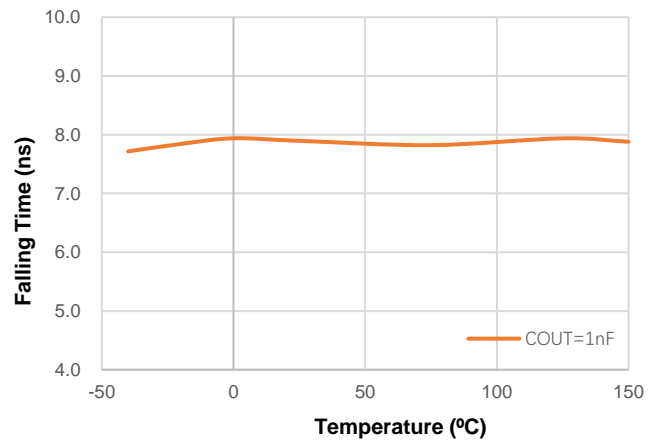


Figure 4. Output Falling Time vs Temperature

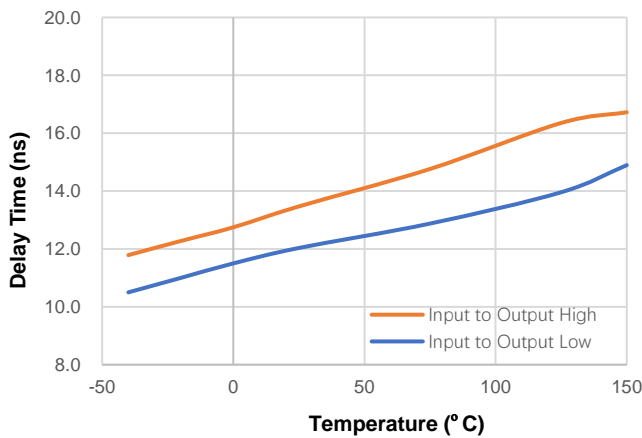


Figure 5. Input to Output Propagation Delay vs Temperature

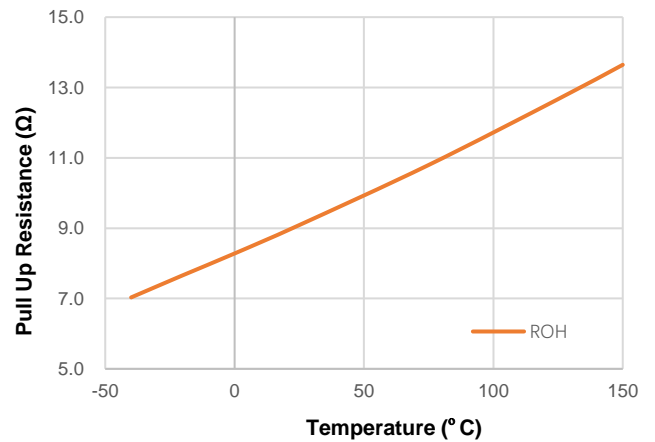


Figure 6. ROH vs Temperature

# SCT52245

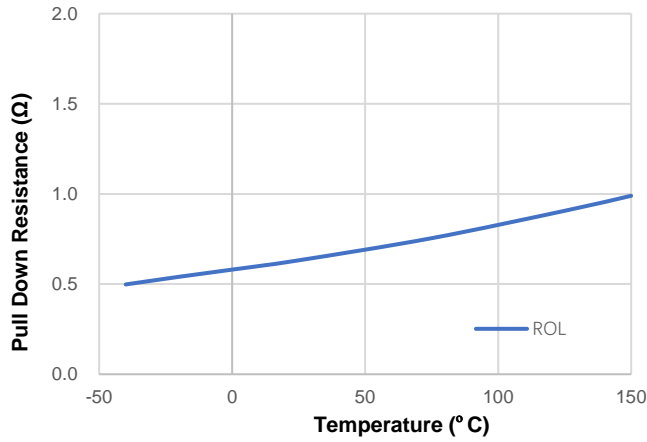


Figure 7. ROL vs Temperature

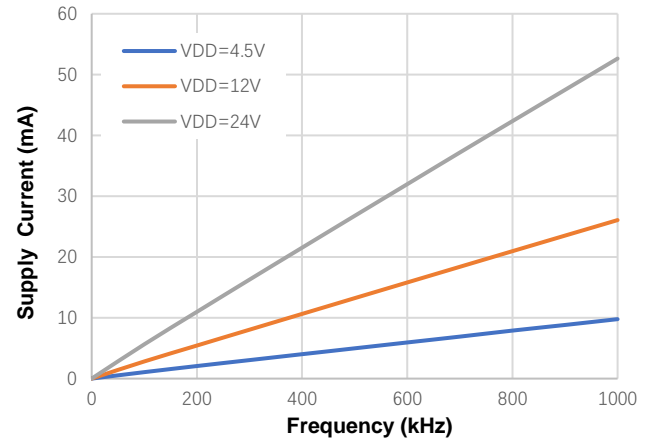


Figure 8. Operation Supply Current vs Frequency,  $C_{OUT}=1nF$

FUNCTIONAL BLOCK DIAGRAM

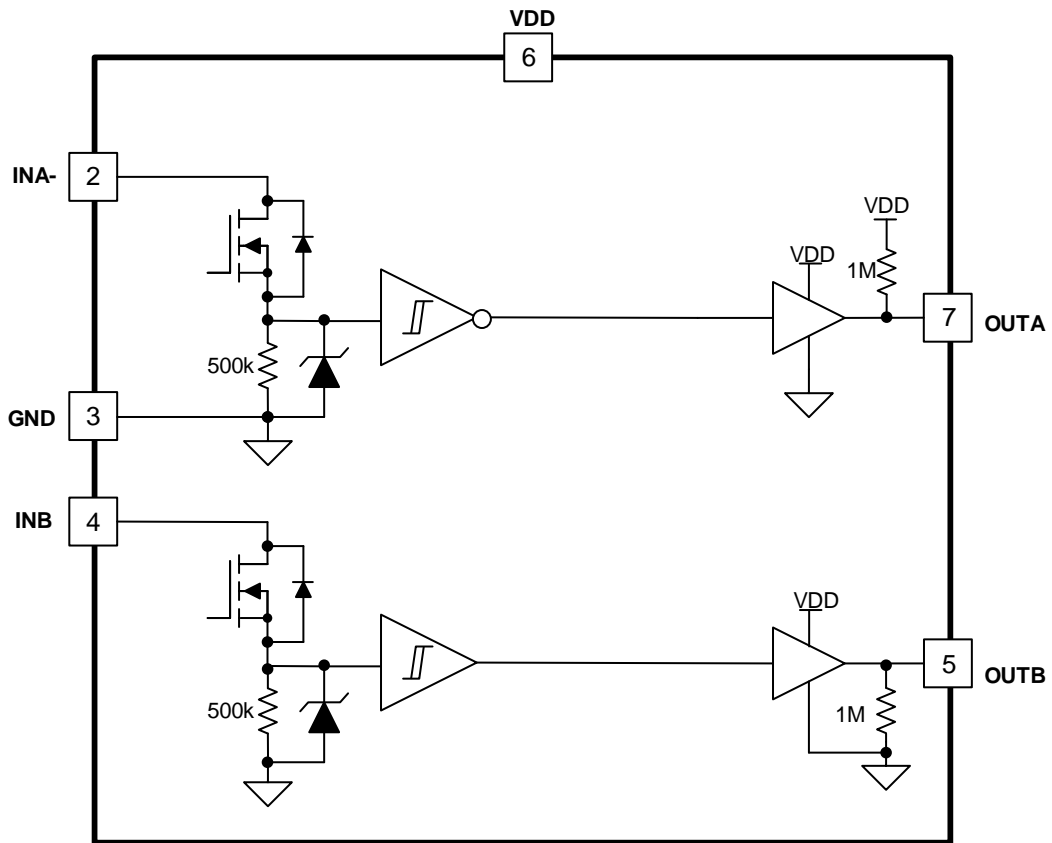


Figure 9. Functional Block Diagram

# SCT52245

## OPERATION

### Overview

The SCT52245 is a dual-channel high-speed low side driver with supporting up to 24V wide supply for both power MOSFET and IGBT. Each channel can source and sink 4A peak current along with the minimum propagation delay 13ns from input to output. The ability to handle -5V DC input increases the noise immunity of driver input stage, the 24V rail-to-rail output improves the SCT52245 output stage robustness during switching load fast transition. Table 1 shows the device output logic truth table.

Table 1: the SCT52245 Device Logic.

INA-	INB	OUTA	OUTB
L	L	H	L
L	H	H	H
H	L	L	L
H	H	L	H
Any(UVLO)	Any(UVLO)	H	L
Floating	Floating	H	L
L	L	H	L
L	H	H	H
H	L	L	L
H	H	L	H

### VDD Power Supply

The SCT52245 operates under a supply voltage range between 4.5V to 24V. For the best high-speed circuit performance, two VDD bypass capacitors in parallel are recommended to prevent noise problems on supply VDD. A 0.1- $\mu$ F surface mount ceramic capacitor must be located as close as possible to the VDD to GND pins of the SCT52245. In addition, a larger capacitor (such as 1- $\mu$ F or 10 $\mu$ F) with relatively low ESR must be connected in parallel, in order to help avoid the unexpected VDD supply glitch. The parallel combination of capacitors presents a low impedance characteristic for the expected current levels and switching frequencies in the application.

### Under Voltage Lockout (UVLO)

SCT52245 device Under Voltage Lock Out (UVLO) rising threshold is typically 4.2 V with 300-mV typical hysteresis. When VDD is rising and the level is still below UVLO threshold, OUTB holds the output low regardless of the status of the inputs and OUTA holds the output high regardless of the status of the inputs. The hysteresis prevents output bouncing when low VDD supply voltages have noise from the power supply.

### Input Stage

The input of SCT52245 is compatible on TTL input-threshold logic that is independent of the VDD supply voltage. With typically high threshold = 2.1 V and typically low threshold = 1 V, the logic level thresholds are conveniently driven with PWM control signals derived from 3.3-V and 5-V digital power-controller devices. Wider hysteresis offers enhanced noise immunity compared to traditional TTL logic implementations, where the hysteresis is typically less than 0.5V. SCT52245 also features tight control of the input pin threshold voltage that ensures stable operation



across temperature. The very low input parasitic capacitance on the input pins increases switching speed and reduces the propagation delay.

## Output Stage

The SCT52245 output stage features the pull up structure with P-type MOSFET PM1 and N-type MOSFET NM1 in parallel, as shown in Figure 12. PM1 provides the pull up capability when OUT approaches VDD and the NM1 holds off state, which guarantees the driver output is up to VDD rail. The measurable on-resistance  $R_{OH}$  in steady state is the conduction resistance of PM1. NM1 provides a narrow instant peak sourcing current up to 4A to eliminate the turn on time and delay. During the output turn on transition, the equivalent hybrid pull on transient resistance is  $1.5R_{OL}$ , which is much lower than the DC measured  $R_{OH}$ .

The N-type MOSFET NM2 composes the output stage pull down structure; the  $R_{OL}$  is the DC measurement and represents the pull down impedance. The output stage of SCT52245 provides rail-to-rail operation, and is able to supply 4A sourcing and 4A sinking peak current. The presence of the MOSFET-body diodes also offers low impedance to switching overshoots and undershoots. The outputs of the dual channel drivers are designed to withstand 500-mA reverse current without either damaging the device or logic malfunction.

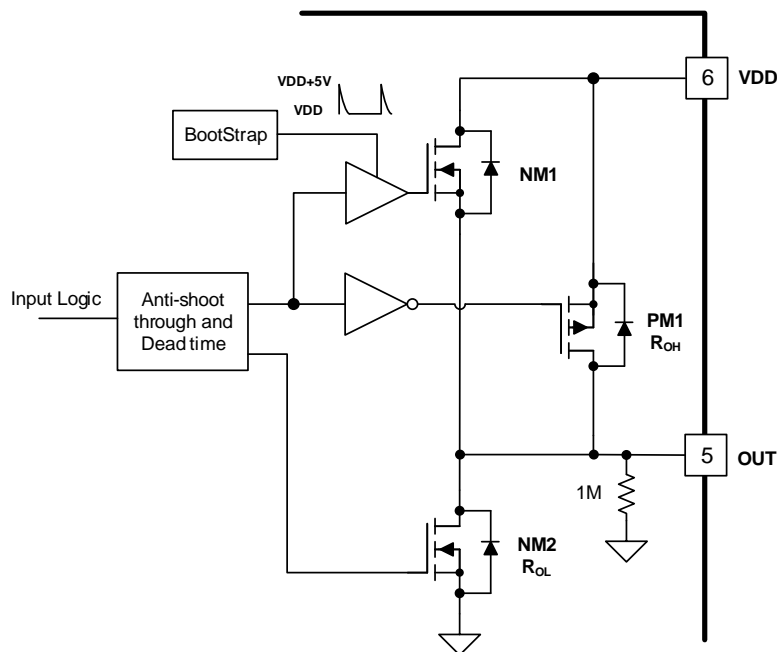


Figure 10. SCT52245 Channel-B Output Stage

## Thermal Shutdown

Once the junction temperature in the SCT52245 exceeds 170° C, the thermal sensing circuit stops switching until the junction temperature falling below 145° C, and the device restarts. Thermal shutdown prevents the damage on device during excessive heat and power dissipation condition.

# SCT52245

## APPLICATION INFORMATION

### Typical Application

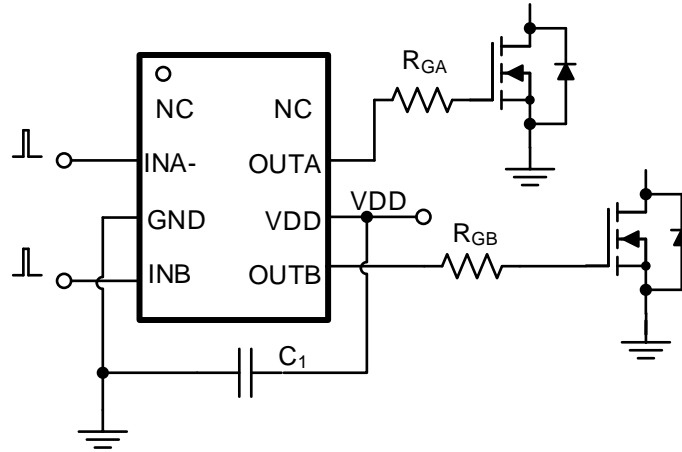


Figure 11. Dual Channel Driver Typical Application

### Driver Power Dissipation

Generally, the power dissipated in the SCT52245 depends on the gate charge required of the power device ( $Q_g$ ), switching frequency, and use of external gate resistors. The SCT52245 features very low quiescent currents and internal logic to eliminate any shoot-through in the output driver stage, their effect on the power dissipation within the gate driver is negligible.

For the pure capacitive load, the power loss of each channel in SCT52245 is:

$$P_G = C_{Load} * V_{DD}^2 * f_{SW} \quad (1)$$

Where

- $V_{DD}$  is supply voltage
- $C_{Load}$  is the output capacitance
- $f_{SW}$  is the switching frequency

For the the switching load of power MOSFET, the power loss of each channel in the SCT52245 is shown in equation (2), where charging a capacitor is determined by using the equivalence  $Q_g = C_{LOAD}V_{DD}$ . The gate charge includes the effects of the input capacitance plus the added charge needed to swing the drain voltage of the power device as it switches between the ON and OFF states. Manufacturers provide specifications that provide the typical and maximum gate charge, in nC, to switch the device under specified conditions.

$$P_G = Q_g * V_{DD} * f_{SW} \quad (2)$$

Where

- $Q_g$  is the gate charge of the power device
- $f_{SW}$  is the switching frequency
- $V_{DD}$  is the supply voltage

If  $R_G$  applied between driver and gate of power device to slow down the power device transition, the power dissipation of the driver shows as below:

$$P_G = \frac{1}{2} * Q_g * V_{DD} * f_{SW} * \left( \frac{R_{OL}}{R_{OL} + R_G} + \frac{R_{OH}}{R_{OH} + R_G} \right) \quad (3)$$

Where

- $R_{OH}$  is the equivalent pull up resistance of SCT52245
- $R_{OL}$  is the pull down resistance of SCT52245
- $R_G$  is the gate resistance between driver output and gate of power device.

# SCT52245

## Application Waveforms

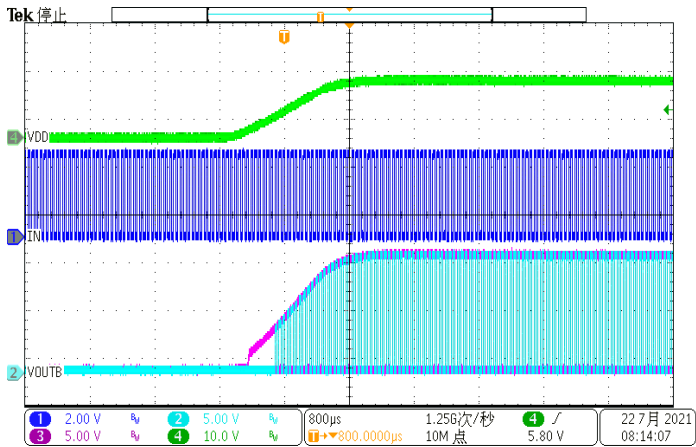


Figure 12. VDD Power ON

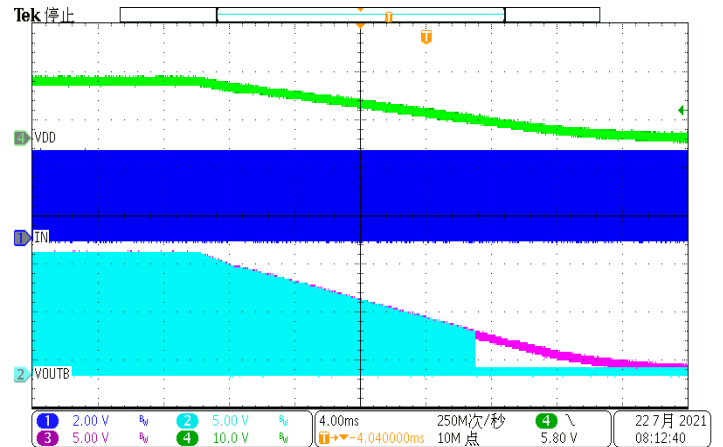


Figure 13. VDD Power OFF

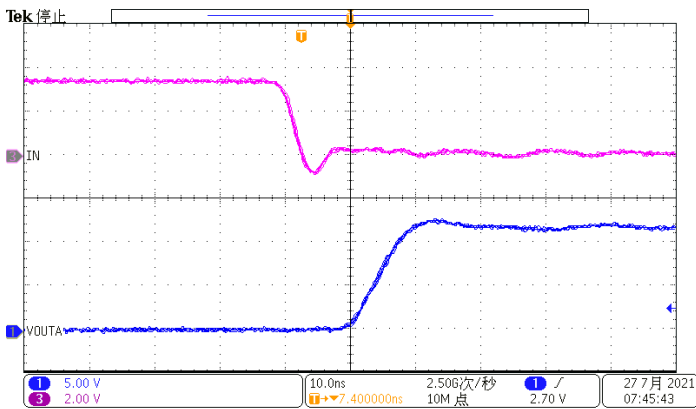


Figure 14. OUTA Switching Rise (Load = 1nF)

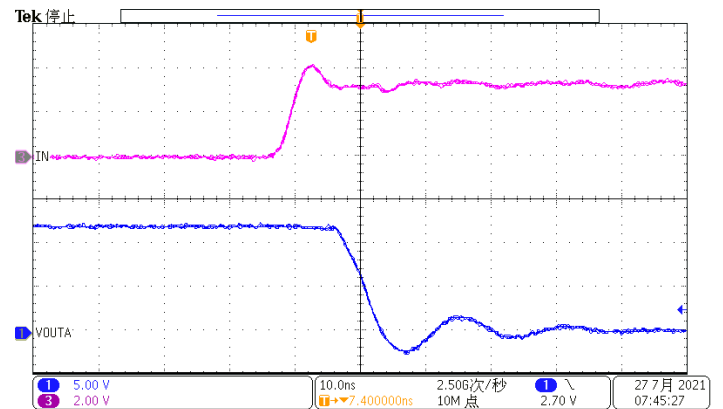


Figure 15. OUTA Switching Fall (Load = 1nF)

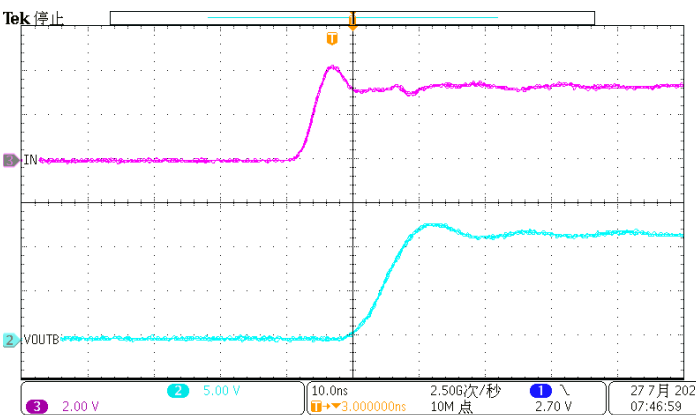


Figure 16. OUTB Switching Rise (Load = 1nF)

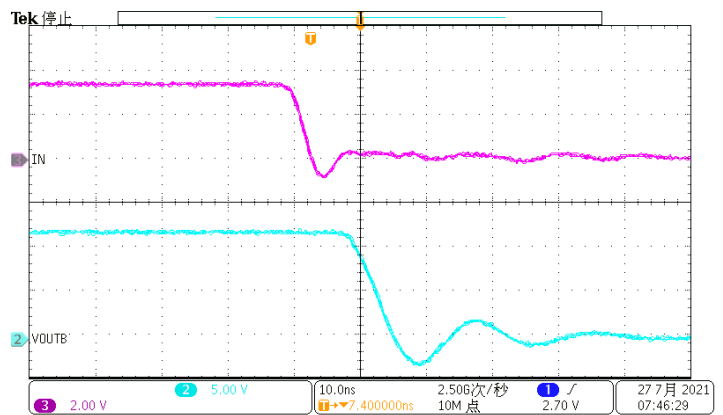


Figure 17. OUTB Switching Fall (Load = 1nF)

## Layout Guideline

The SCT52245 provides the 4A output driving current and features very short rising and falling time at the power devices gate. The high di/dt causes driver output unexpected ringing when the driver output loop is not designed well. The regulator could suffer from malfunction and EMI noise problems if the power device gate has serious ringing. Below are the layout recommendations with using SCT52245 and Figure 18 is the layout example.

Put the SCT52245 as close as possible to the power device to minimize the gate driving loop including the driver output and power device gate. The power supply decoupling capacitors needs to be close to the VDD pin and GND pin to reduce the supply ripple.

Star-point grounding is recommended to minimize noise coupling from one current loop to the other. The GND of the driver connects to the other circuit nodes such as source of power MOSFET or ground of PWM controller at single point. The connected paths must be as short as possible to reduce parasitic inductance. A ground plane is to provide noise shielding and thermal dissipation as well.

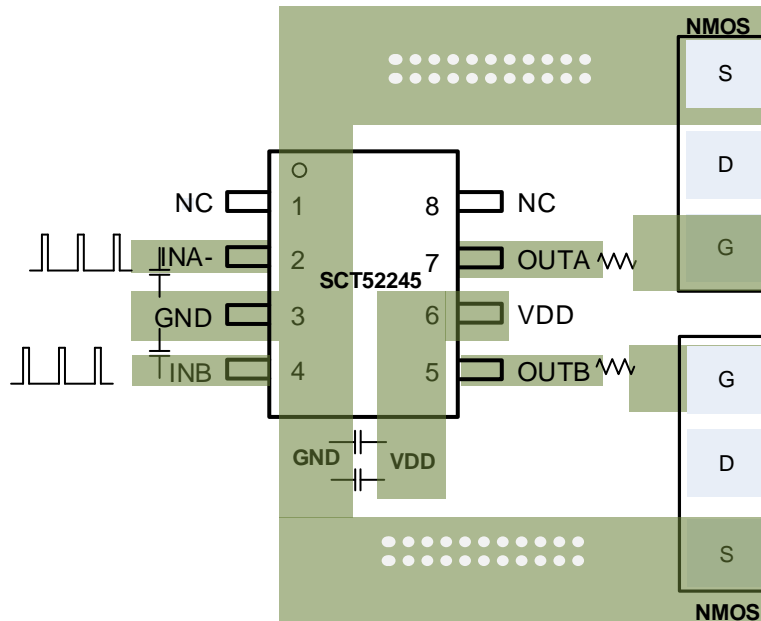


Figure 18. SCT52245 PCB Layout Example

## Thermal Considerations

The maximum IC junction temperature should be restricted to 150°C under normal operating conditions. Calculate the maximum allowable dissipation,  $P_{D(max)}$ , and keep the actual power dissipation less than or equal to  $P_{D(max)}$ . The maximum-power-dissipation limit is determined using Equation (4).

$$P_{D(MAX)} = \frac{150 - T_A}{R_{\theta JA}} \quad (4)$$

where

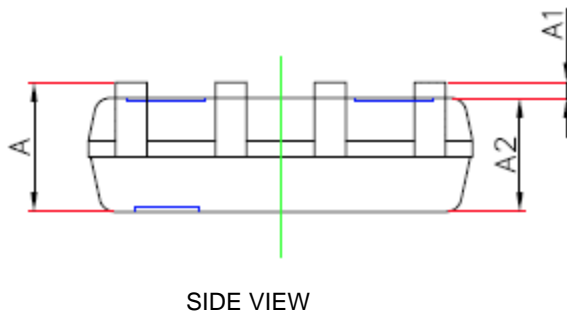
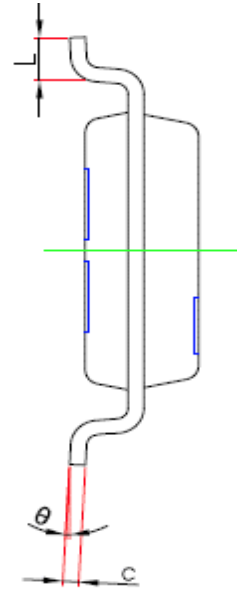
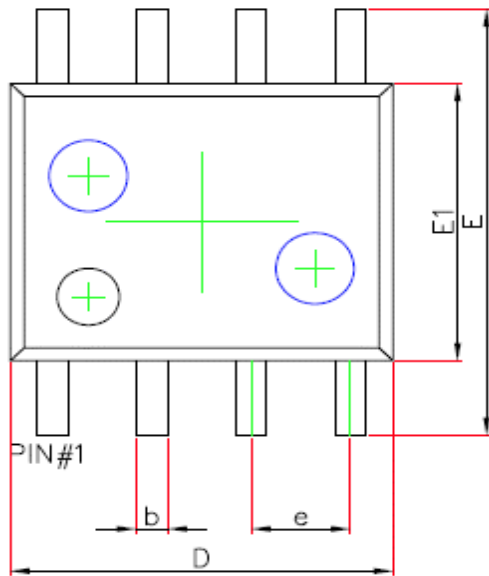
- $T_A$  is the maximum ambient temperature for the application.
- $R_{\theta JA}$  is the junction-to-ambient thermal resistance given in the Thermal Information table.

# SCT52245

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The real junction-to-ambient thermal resistance  $R_{\theta JA}$  of the package greatly depends on the PCB type, layout, and environmental factor. Soldering the ground pin to a large ground plate enhance the thermal performance. Using more vias connects the ground plate on the top layer and bottom layer around the IC without solder mask also improves the thermal capability.

## PACKAGE INFORMATION (SOP-8)



SYMBOL	Unit: Millimeter		
	MIN	TYP	MAX
A	1.45	---	1.75
A1	0.1	---	0.25
A2	1.35	---	1.55
b	0.33	---	0.51
c	0.17	---	0.25
D	4.7		5.1
E	5.8		6.2
E1	3.8		4.0
e	1.27BSC		
L	0.4		1.27
θ	0°		8°

### NOTE:

1. Drawing proposed to be made a JEDEC package outline MO-220 variation.
2. Drawing not to scale.
3. All linear dimensions are in millimeters.
4. Thermal pad shall be soldered on the board.
5. Dimensions of exposed pad on bottom of package do not include mold flash.
6. Contact PCB board fabrication for minimum solder mask web tolerances between the pins.

# SCT52245

## TAPE AND REEL INFORMATION

